



## N-Channel 240-V (D-S) MOSFET

PRODUCT SUMMARY				
Part Number	$V_{(BR)DSS}$ Min (V)	$r_{DS(on)}$ Max ( $\Omega$ )	$V_{GS(th)}$ (V)	$I_D$ Min (mA)
TN2460L	240	60 @ $V_{GS} = 10$ V	0.5 to 1.8	75
TN2460T		60 @ $V_{GS} = 10$ V	0.5 to 1.8	51

### FEATURES

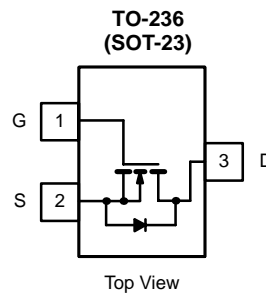
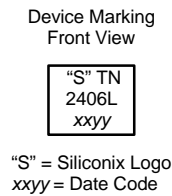
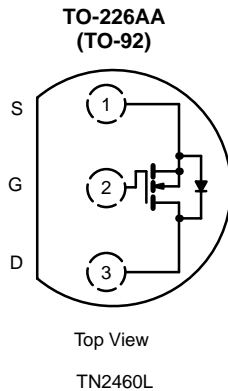
- Low On-Resistance: 40  $\Omega$
- Secondary Breakdown Free: 260 V
- Low Power/Voltage Driven
- Low Input and Output Leakage
- Excellent Thermal Stability

### BENEFITS

- Low Offset Voltage
- Full-Voltage Operation
- Easily Driven Without Buffer
- Low Error Voltage
- No High-Temperature "Run-Away"

### APPLICATIONS

- High-Voltage Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Transistors, etc.
- Telephone Mute Switches, Ringer Circuits
- Power Supply, Converters
- Motor Control



Marking Code: T2w//  
T2 = Part Number Code for TN2460T  
w = Week Code  
// = Lot Traceability

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)				
Parameter	Symbol	TN2460L	TN2460T	Unit
Drain-Source Voltage	$V_{DS}$	240	240	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	$\pm 20$	
Continuous Drain Current ( $T_J = 150^\circ\text{C}$ )	$I_D$	$T_A = 25^\circ\text{C}$	75	mA
		$T_A = 100^\circ\text{C}$	48	
Pulsed Drain Current <sup>a</sup>	$I_{DM}$	800	400	
Power Dissipation	$P_D$	$T_A = 25^\circ\text{C}$	0.8	W
		$T_A = 100^\circ\text{C}$	0.32	
Thermal Resistance, Junction-to-Ambient	$R_{thJA}$	156	350	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150		$^\circ\text{C}$

Notes

a. Pulse width limited by maximum junction temperature.

SPECIFICATIONS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ <sup>a</sup>	Max	
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}, I_D = 10\ \mu\text{A}$	240	260		V
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	0.5	1.65	1.8	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$ $T_J = 125^\circ\text{C}$		$\pm 5$	$\pm 10$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 120\text{ V}, V_{GS} = 0\text{ V}$ $T_J = 125^\circ\text{C}$			0.1 5	$\mu\text{A}$
On-State Drain Current <sup>b</sup>	$I_{D(on)}$	$V_{DS} = 10\text{ V}, V_{GS} = 10\text{ V}$	75	140		mA
		$V_{DS} = 10\text{ V}, V_{GS} = 4.5\text{ V}$	20	130		
Drain-Source On-Resistance <sup>b</sup>	$r_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 0.05\text{ A}$		38	60	$\Omega$
		$V_{GS} = 4.5\text{ V}, I_D = 0.02\text{ A}$ $T_J = 125^\circ\text{C}$		40 75	60 120	
Forward Transconductance <sup>b</sup>	$g_{fs}$	$V_{DS} = 10\text{ V}, I_D = 0.05\text{ A}$	30	70		
<b>Dynamic</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		14	30	pF
Output Capacitance	$C_{oss}$		4	15		
Reverse Transfer Capacitance	$C_{rss}$		1	10		
<b>Switching<sup>c</sup></b>						
Turn-On Time	$t_{ON}$	$V_{DD} = 25\text{ V}, R_L = 500\ \Omega$ $I_D \cong 0.05\text{ A}, V_{GEN} = 10\text{ V}, R_G = 25\ \Omega$		8	20	ns
Turn-Off Time	$t_{OFF}$		20	35		

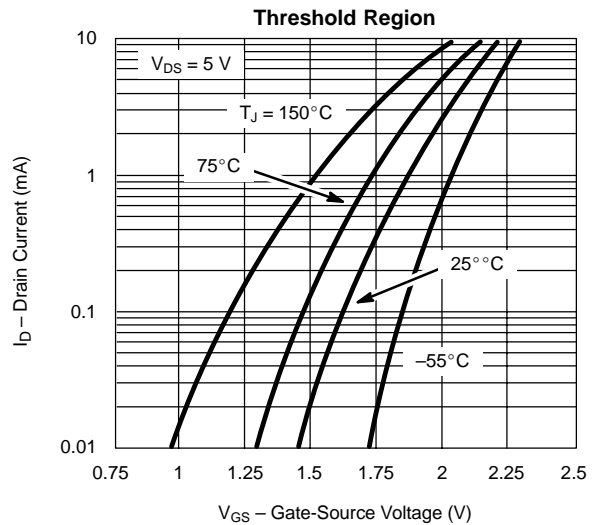
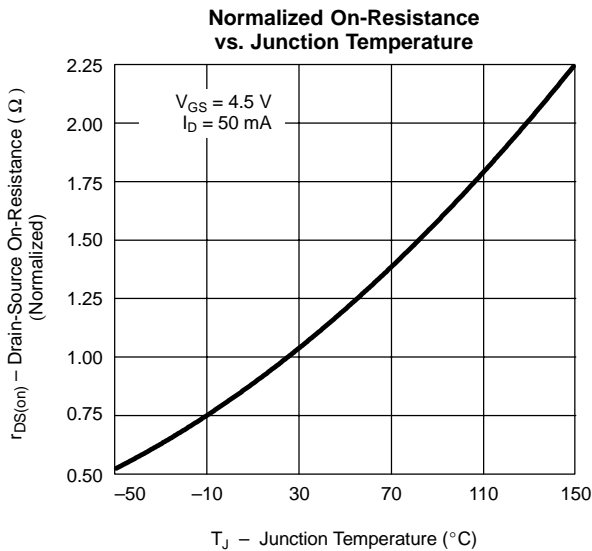
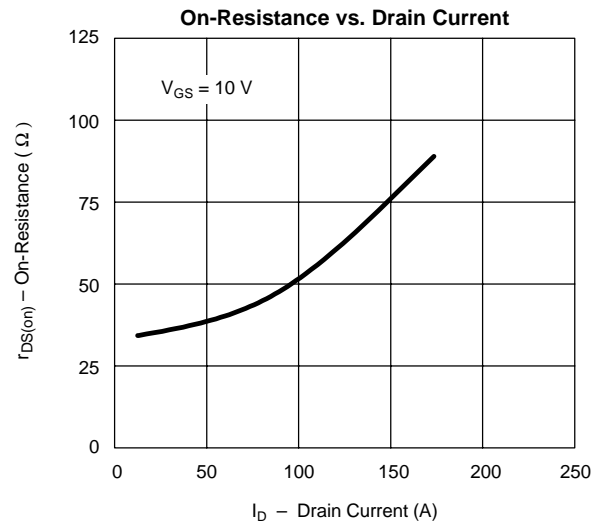
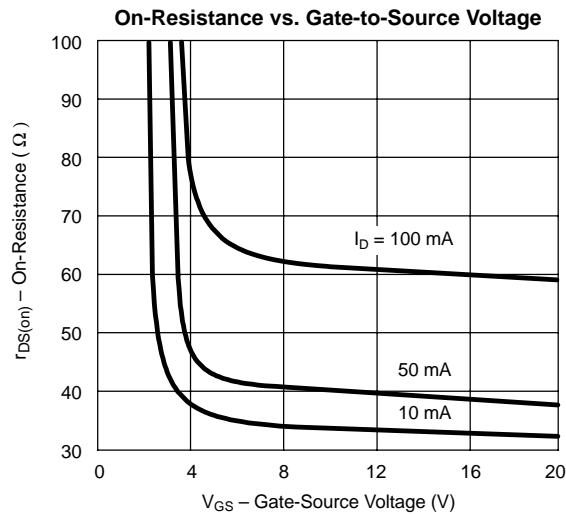
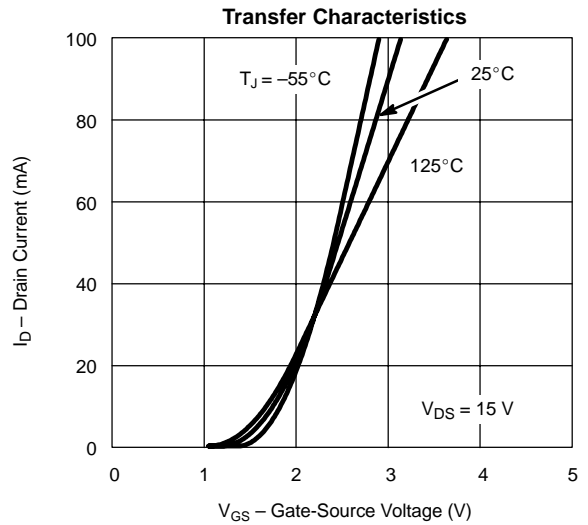
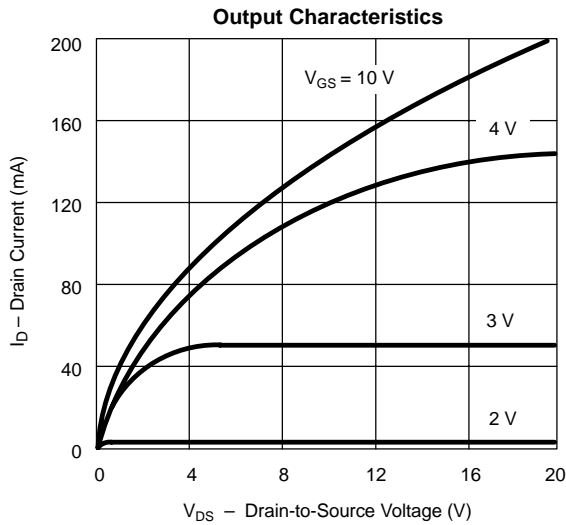
## Notes

- a. For DESIGN AID ONLY, not subject to production testing.  
b. Pulse test:  $PW \leq 80\ \mu\text{s}$  duty cycle  $\leq 1\%$ .  
c. Switching time is essentially independent of operating temperature.

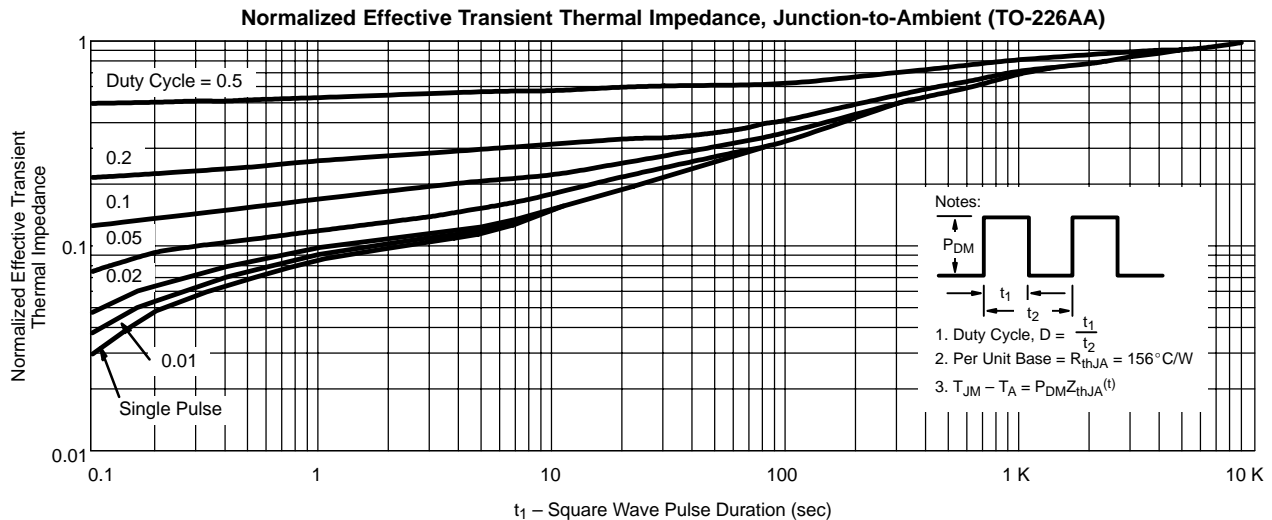
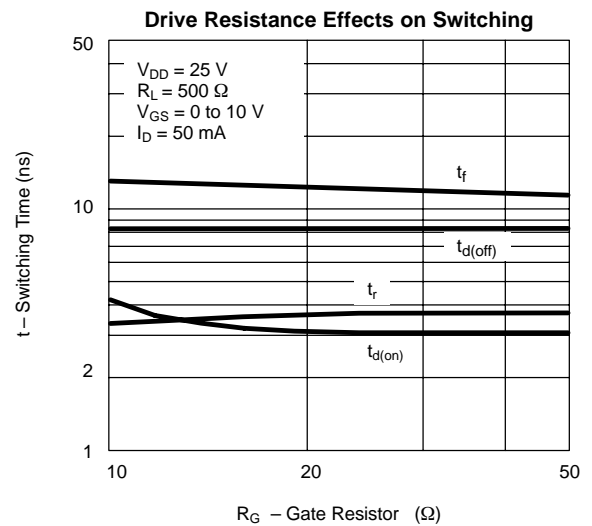
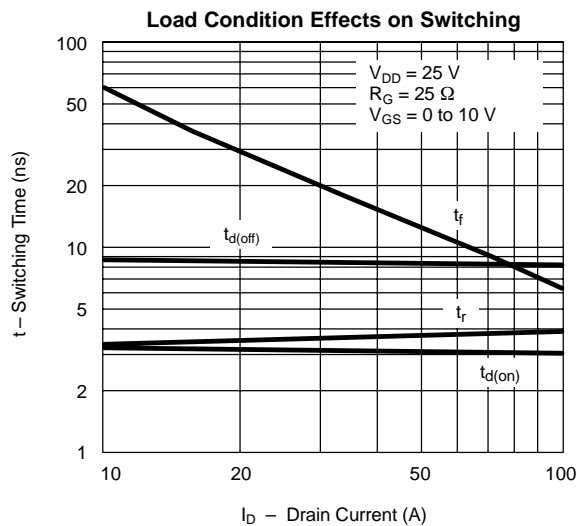
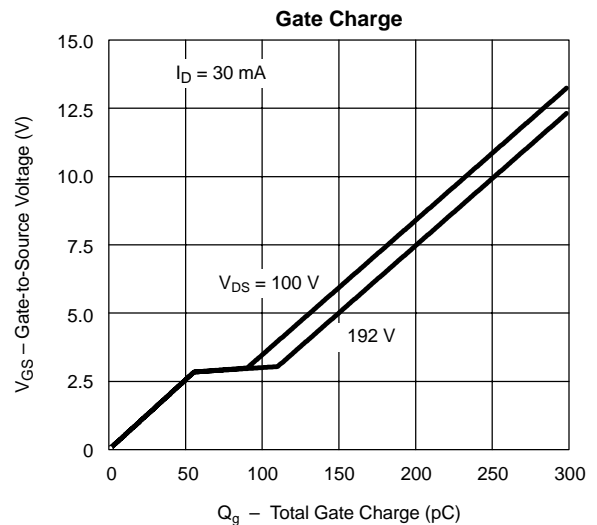
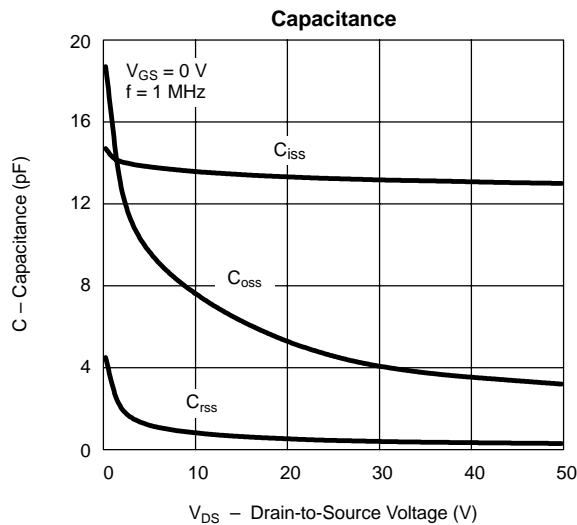
VNDN24



**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**



### TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)





## Disclaimer

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